AUTOMOTIVE

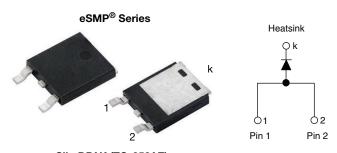
COMPLIANT

HALOGEN FREE



Vishay Semiconductors

Ultralow V_F Ultrafast Rectifier, 6 A FRED Pt®



SlimDPAK (TO-252AE)

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	6 A				
V _R	600 V				
V _F at I _F	0.98 V				
t _{rr} (typ.)	34 ns				
T _J max.	175 °C				
Package	SlimDPAK (TO-252AE)				
Circuit configuration	Single				

FEATURES

- Ultrafast recovery time, extremely low V_F and soft recovery
- For PFC CCM operation
- · Low forward voltage drop, low power losses
- · Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
 - Automotive ordering code: base P/NHM3, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters, or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V_{RRM}		600	V	
Average rectified forward current	I _{F(AV)}	T _C = 158 °C	6	۸	
Non-repetitive peak surge current	I _{FSM}	$T_J = 25$ °C, 10 ms sine pulse wave	80	1 A	
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	Ι _R = 100 μΑ	600	-	-	.,
Forward voltage	V _F	I _F = 6 A	-	1.15	1.35	- V
		I _F = 6 A, T _J = 150 °C	-	0.98	1.15	
Devenue le alcene accoment	I _R	V _R = V _R rated	-	-	5	
Reverse leakage current		$T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	-	125	μA
Junction capacitance	C _T	V _R = 600 V	-	10	-	pF

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	45	-	
		$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	34	-	
Reverse recovery time	t _{rr}	I _F = 0.5 A, I _R = 1 A, I _{RR} = 0.25 A		-	-	50	ns
		T _J = 25 °C	I _F = 6 A dI _F /dt = 500 A/μs V _R = 400 V	-	65	-	
		T _J = 125 °C		-	90	-	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	9.5	-	۸
		T _J = 125 °C		-	13.5	-	A
Reverse recovery charge	0	T _J = 25 °C		-	320	-	nC
	Q_{rr}	T _J = 125 °C		-	620	-	110

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to mount	R_{thJM}		-	-	2.5	°C/W
Weight			-	0.20	-	g
Marking device		Case style SlimDPAK (TO-252AE)		6EV	′L06	

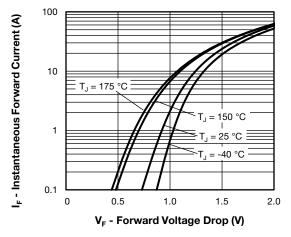


Fig. 1 - Typical Forward Voltage Drop Characteristics

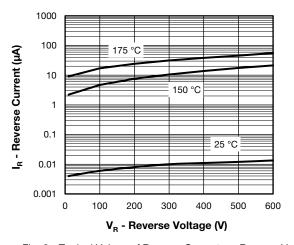


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

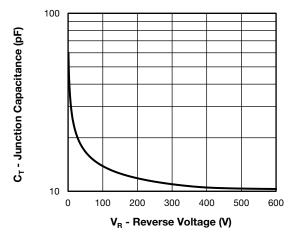


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



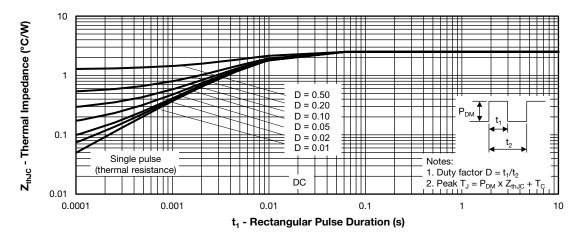


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

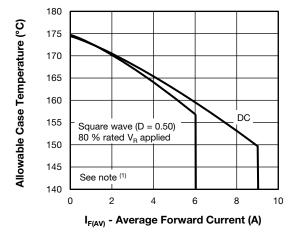


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

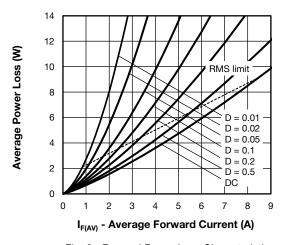


Fig. 6 - Forward Power Loss Characteristics

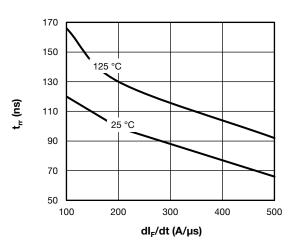


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

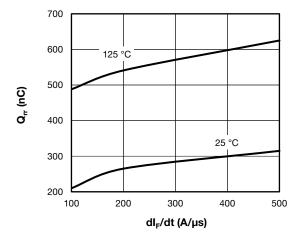
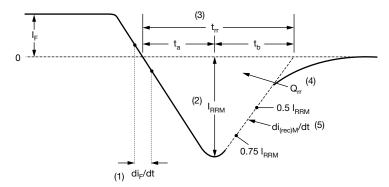


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

 $[\]begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D)}; I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$

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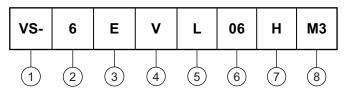


- (1) di_F/dt rate of change of current through zero crossing
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}
- (2) I_{RRM} peak reverse recovery current
- $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (5) di_{(rec)M}/dt peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- Current rating (6 = 6 A)
- 3 Circuit configuration:

E = single die

- 4 V = SlimDPAK
- 5 Process type:

L = ultralow V_F ultrafast rectifier

- 6 Voltage code (06 = 600 V)
- 7 H = AEC-Q101 qualified
- 8 Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION		
VS-6EVL06HM3/I	0.20	I	4500	13"diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96081			
Part marking information	www.vishay.com/doc?96085			
Packaging information	www.vishay.com/doc?88869			



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SlimDPAK

DIMENSIONS in inches (millimeters)





Mounting Pad Layout







Legal Disclaimer Notice

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